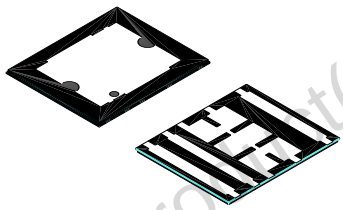
STK22N6F3

N-channel 60 V, 0.0055 Ω, 22 A, PolarPAK® STripFET™ Power MOSFET

Features

Type	V_{DSS}	$R_{DS(on)}$ max
STK22N6F3	60 V	< 0.006 Ω

- Ultra low top and bottom junction to case thermal resistance
- Extremely low on-resistance $R_{DS(on)}$
- Very low switching gate charge
- Fully encapsulated die
- 100% matte tin finish (in compliance with the 2002/95/EC european directive)
- High avalanche ruggedness
- PolarPAK® is a trademark of VISHAY



PolarPAK®

Application

- Switching applications

Description

This STripFET™ III Power MOSFET technology is among the latest improvements, which have been especially tailored to minimize on-state resistance providing superior switching performances.

Figure 1. Internal schematic diagram

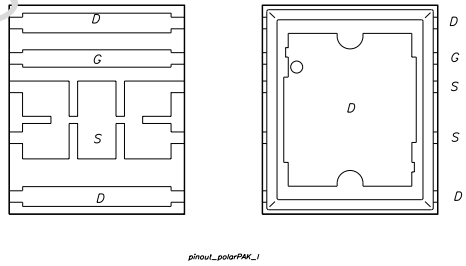


Table 1. Device summary

Order code	Marking	Package	Packaging
STK22N6F3	2263	PolarPAK®	Tape and reel

Obsolete Product(s) - Obsolete Product(s)

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2 Electrical characteristics 4

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Obsolete Product(s) - Obsolete Product(s)
Obsolete Product(s) - Obsolete Product(s)

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage (V_{GS} = 0)	60	V
V_{GS}	Gate-source voltage	± 20	V
I_D (1)	Drain current (continuous) at T_C = 25°C	22	A
I_D	Drain current (continuous) at T_C = 100°C	13.7	A
I_{DM} (2)	Drain current (pulsed)	88	A
P_{TOT} (1)	Total dissipation at T_C = 25°C	5.2	W
	Derating factor	0.0416	W/°C
E_{AS} (3)	Single pulse avalanche energy	800	mJ
T_j T_{stg}	Operating junction temperature Storage temperature	-55 to 150	°C

1. When mounted on FR-4 board of 1inch^2, 2 oz Cu and ≤ 10 sec
2. Pulse width limited by package
3. Starting T_J = 25 °C, I_D = 11 A, V_{DD} = 48 V

Table 3. Thermal data

Symbol	Parameter	Typ.	Max.	Unit
Rthj-amb(1)	Thermal resistance junction-amb	20	24	°C/W
Rthj-c(2)	Thermal resistance junction-case (top drain)	0.8	1	°C/W
Rthj-c(3)	Thermal resistance junction-case (source)	2.2	2.7	°C/W

1. When mounted on FR-4 board of 1inch^2, 2 oz Cu and ≤ 10sec
2. Steady state
3. Measured at source pin when the device is mounted on FR-4 board in steady state

Obsolete Product(s) - Obsolete Product(s)
Obsolete Product(s) - Obsolete Product(s)

2 Electrical characteristics

(T_{CASE}=25 °C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	I_D = 250 µA, V_{GS}= 0	60	-	-	V
I_{DSS}	Zero gate voltage drain current (V_{GS} = 0)	V_{DS} = Max rating, V_{DS} = Max rating,Tc=125 °C	-	-	10 100	µA µA
I_{GSS}	Gate body leakage current (V_{DS} = 0)	V_{GS} = ± 20V	-	-	±200	nA
$V_{GS(th)}$	Gate threshold voltage	V_{DS}= V_{GS}, I_D = 250 µA	2	-	4	V
$R_{DS(on)}$	Static drain-source on resistance	V_{GS}= 10 V, I_D= 11 A	-	0.0055	0.006	Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{iss} C_{oss} C_{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V_{DS} =25 V, f=1 MHz, V_{GS}=0	-	2500 536 44	-	pF pF pF
Q_g Q_{gs} Q_{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD}=48 V, I_D = 22 A V_{GS} =10 V *Figure 14*	-	41 12 10	-	nC nC nC
R_G	Gate input resistance	f=1 MHz Gate DC Bias = 0 Test signal level = 20 mV open drain	-	0.9	-	Ω

Table 6. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ t_r	Turn-on delay time Rise time	V_{DD}= 30 V, I_D= 11 A, R_G=4.7 Ω, V_{GS}= 10 V *Figure 13*	-	16 14	-	ns ns
$t_{d(off)}$ t_f	Turn-off delay time Fall time	V_{DD}=30 V, I_D= 11 A, R_G=4.7 Ω, V_{GS}= 10 V *Figure 13*	-	28 5	-	ns ns

Obsolete Product(s) - Obsolete Product(s)

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD} I_{SDM}(1)	Source-drain current Source-drain current (pulsed)		-	-	22 88	A A
V_{SD}(2)	Forward on voltage	I_{SD}= 22 A, V_{GS}=0	-	-	1.2	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD}= 22 A, di/dt = 100 A/µs, V_{DD}=30 V, Tj=150°C *Figure 18*	-	49 91 3.7	-	ns nC A

1. Pulse width limited by package
2. Pulsed: pulse duration = 300µs, duty cycle 1.5%

Obsolete Product(s) - Obsolete Product(s)
Obsolete Product(s) - Obsolete Product(s)

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

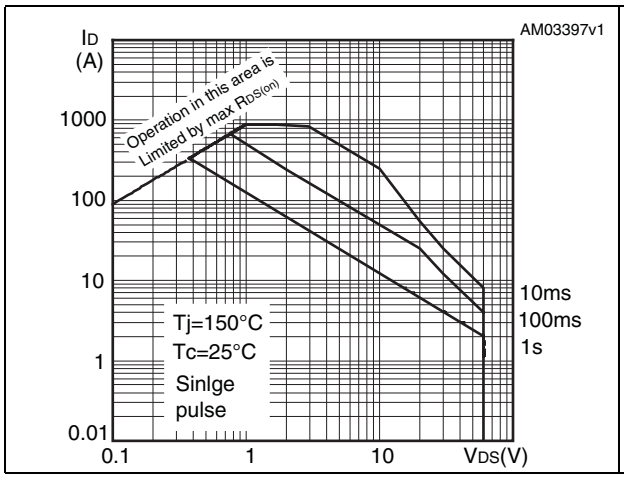


Figure 3. Thermal impedance

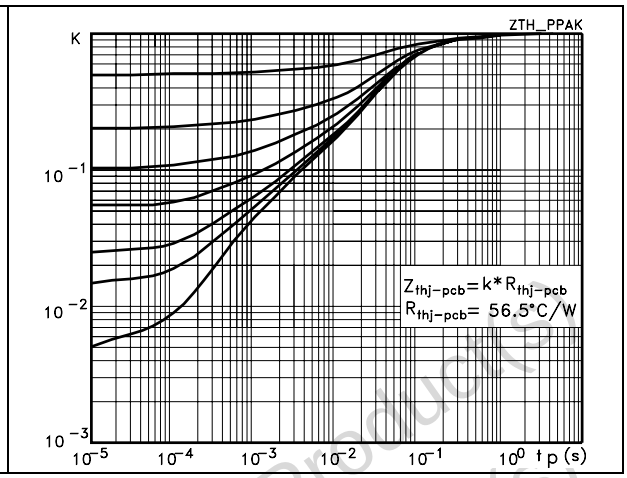


Figure 4. Output characteristics

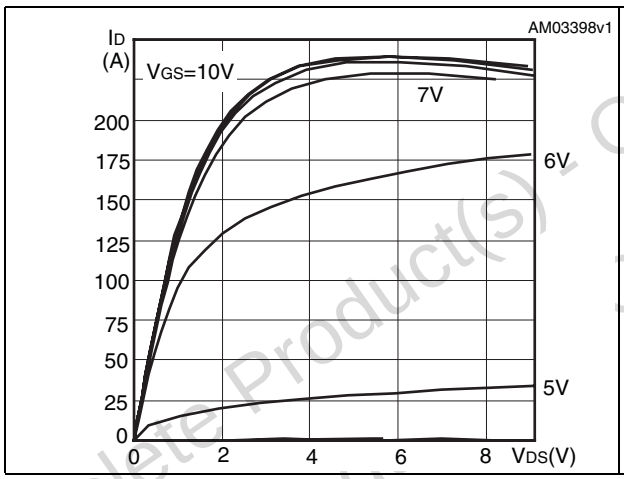


Figure 5. Transfer characteristics

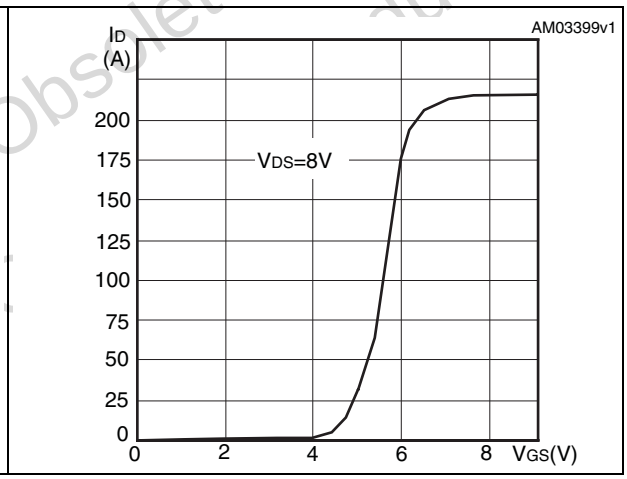


Figure 6. Normalized BV_{DSS} vs temperaure

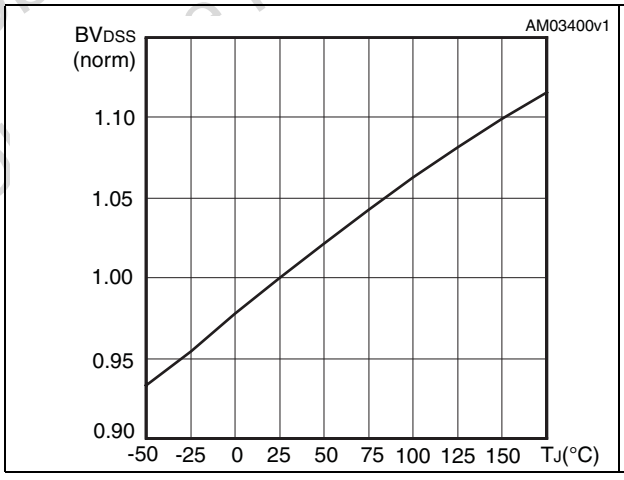
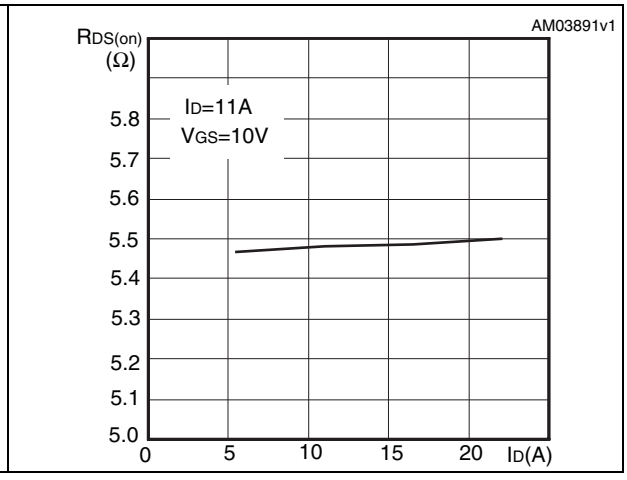


Figure 7. Static drain-source on resistance



Obsolete Product(s) - Obsolete Product(s)

Figure 8. Gate charge vs gate-source voltage

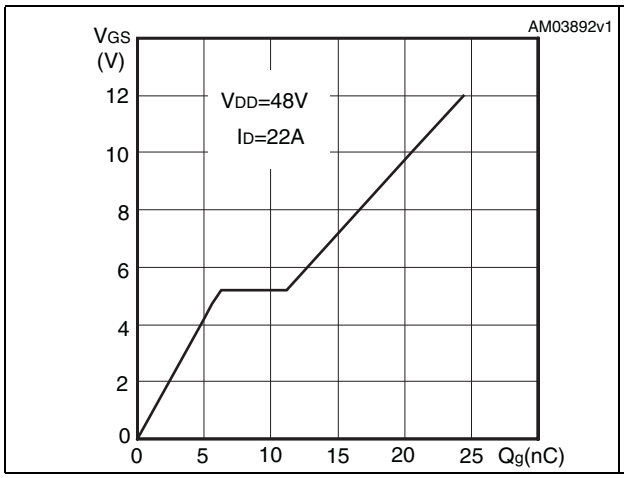


Figure 9. Capacitance variations

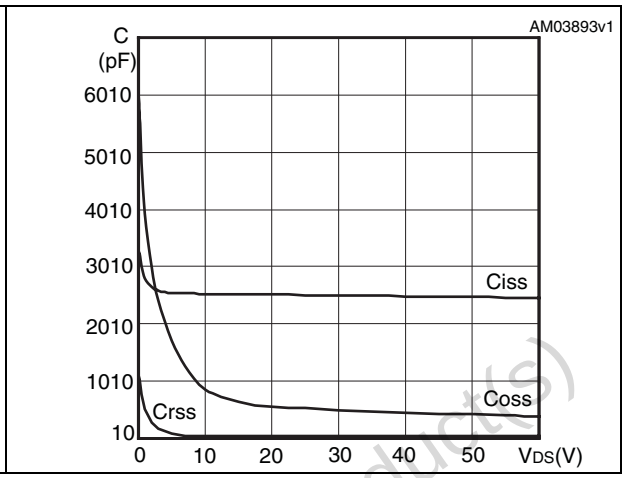


Figure 10. Normalized gate threshold voltage vs temperature

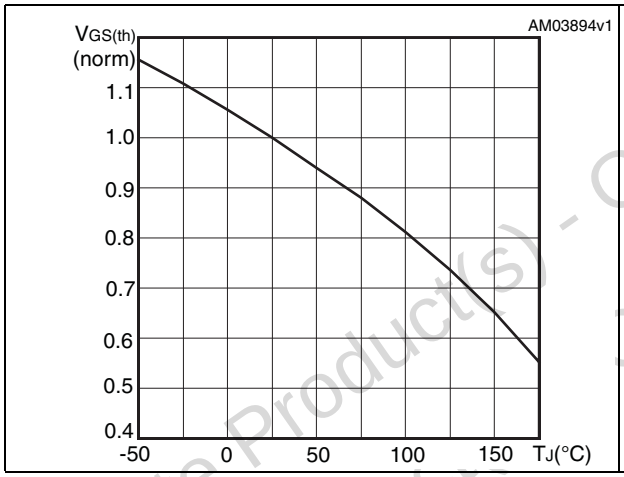


Figure 11. Normalized on resistance vs temperature

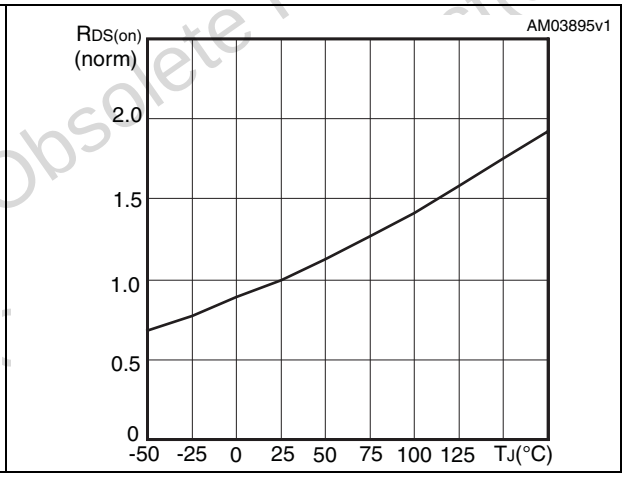
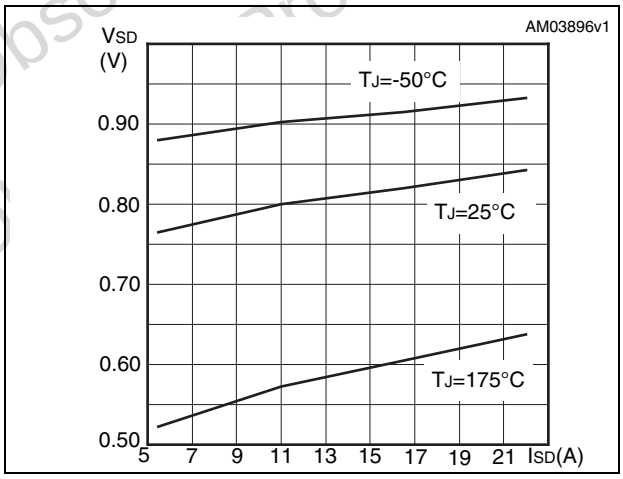


Figure 12. Source-drain diode forward characteristics



Obsolete Product(s) - Obsolete Product(s)

3 Test circuits

Figure 13. Switching times test circuit for resistive load

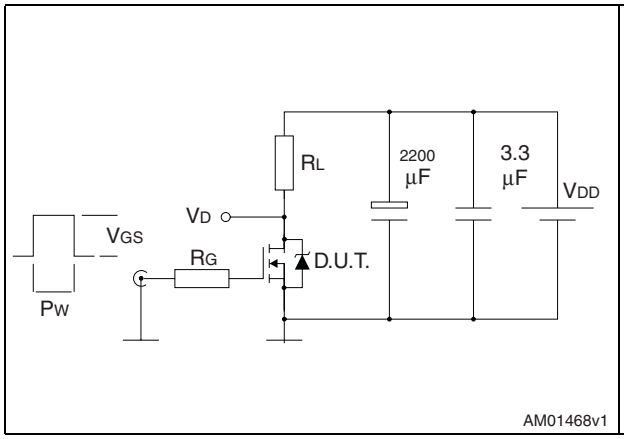


Figure 14. Gate charge test circuit

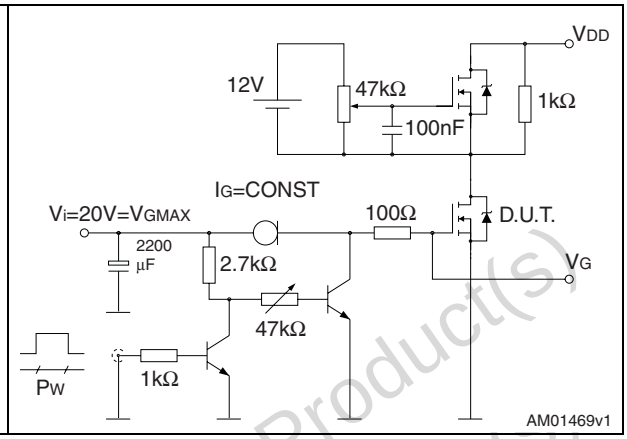


Figure 15. Test circuit for inductive load switching and diode recovery times

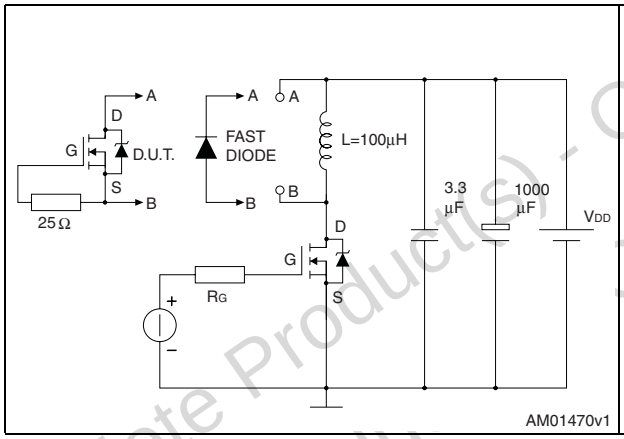


Figure 16. Unclamped inductive load test circuit

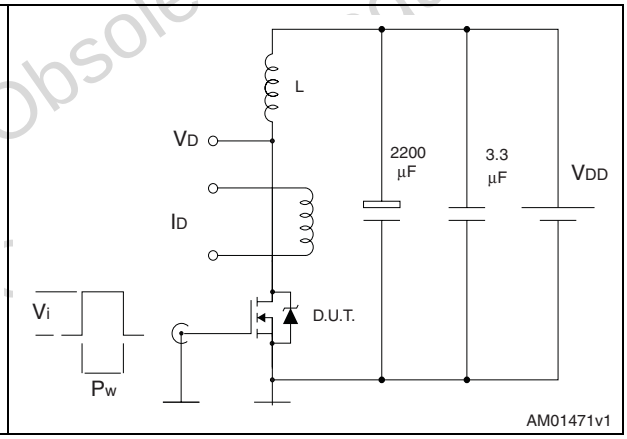


Figure 17. Unclamped inductive waveform

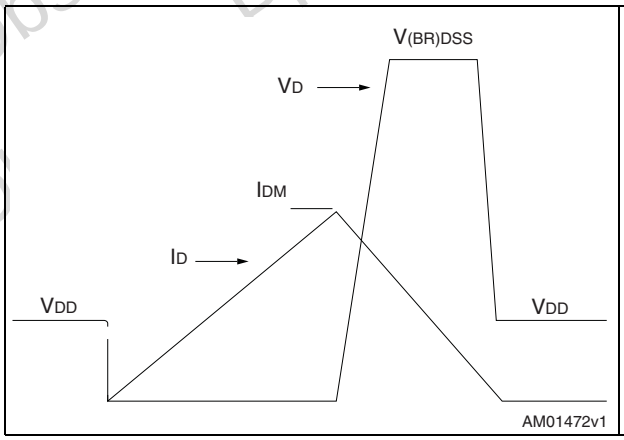
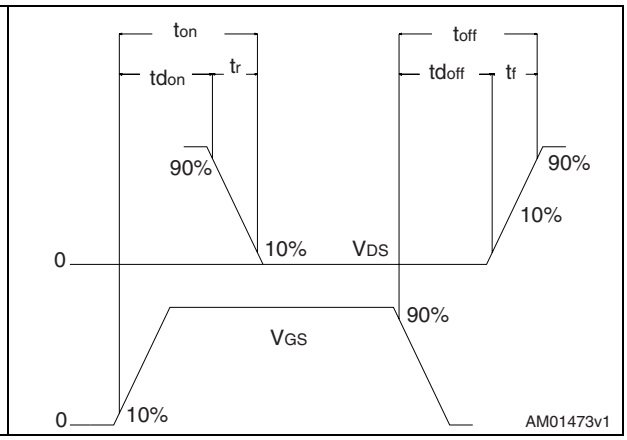
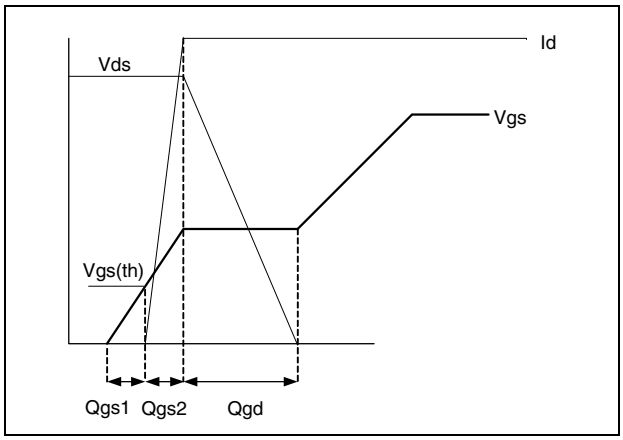


Figure 18. Switching time waveform



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Figure 19. Gate charge waveform



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Obsolete Product(s) - Obsolete Product(s)

4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

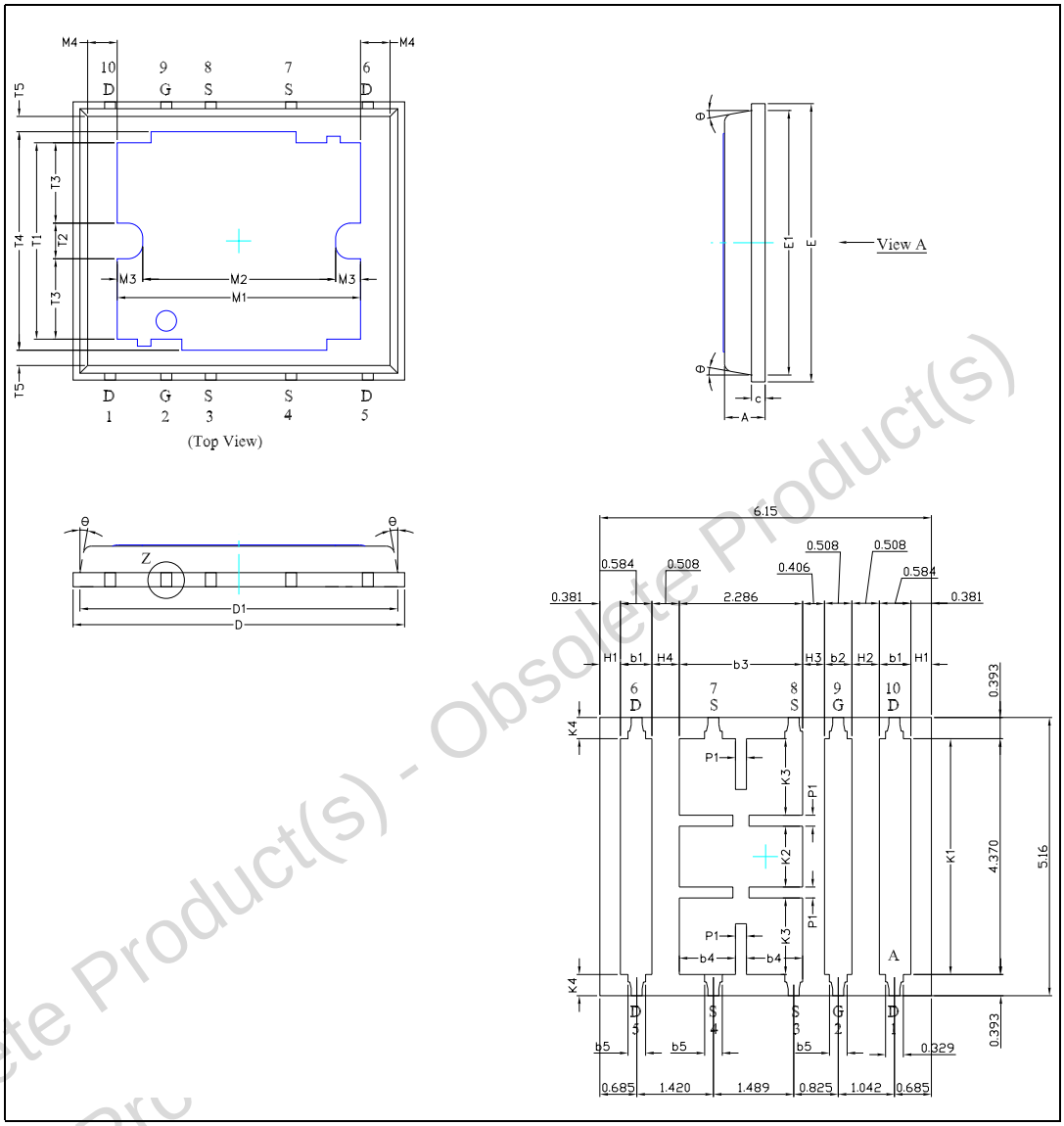
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Table 8. PolarPAK® (option “L”) mechanical data

Ref.	mm			inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.75	0.80	0.85	0.030	0.031	0.033
A1			0.05			0.002
b1	0.48	0.58	0.68	0.019	0.023	0.027
b2	0.41	0.51	0.61	0.016	0.020	0.024
b3	2.19	2.29	2.39	0.086	0.090	0.094
b4	0.89	1.04	1.19	0.035	0.041	0.047
b5	0.23	0.33	0.43	0.009	0.013	0.017
c	0.20	0.25	0.30	0.008	0.010	0.012
D	6	6.15	6.30	0.236	0.242	0.248
D1	5.74	5.89	6.04	0.226	0.232	0.238
E	5.01	5.16	5.31	0.197	0.203	0.209
E1	4.75	4.90	5.05	0.187	0.193	0.199
H1	0.23			0.009		
H2	0.45		0.56	0.018		0.022
H3	0.31	0.41	0.51	0.012	0.016	0.020
H4	0.45		0.56	0.018		0.022
K1	4.22	4.37	4.52	0.166	0.172	0.178
K2	1.08	1.13	1.18	0.043	0.044	0.046
K3	1.37			0.054		
K4	0.24			0.009		
M1	4.30	4.50	4.70	0.169	0.177	0.185
M2	3.43	3.58	3.73	0.135	0.141	0.147
M3	0.22			0.009		
M4	0.05			0.002		
P1	0.15	0.20	0.25	0.006	0.008	0.010
T1	3.48	3.64	4.10	0.137	0.143	0.161
T2	0.56	0.76	0.95	0.022	0.030	0.037
T3	1.20			0.047		
T4	3.90			0.154		
T5		0.18	0.36		0.007	0.014
<	0°	10°	12°	0°	10°	12°

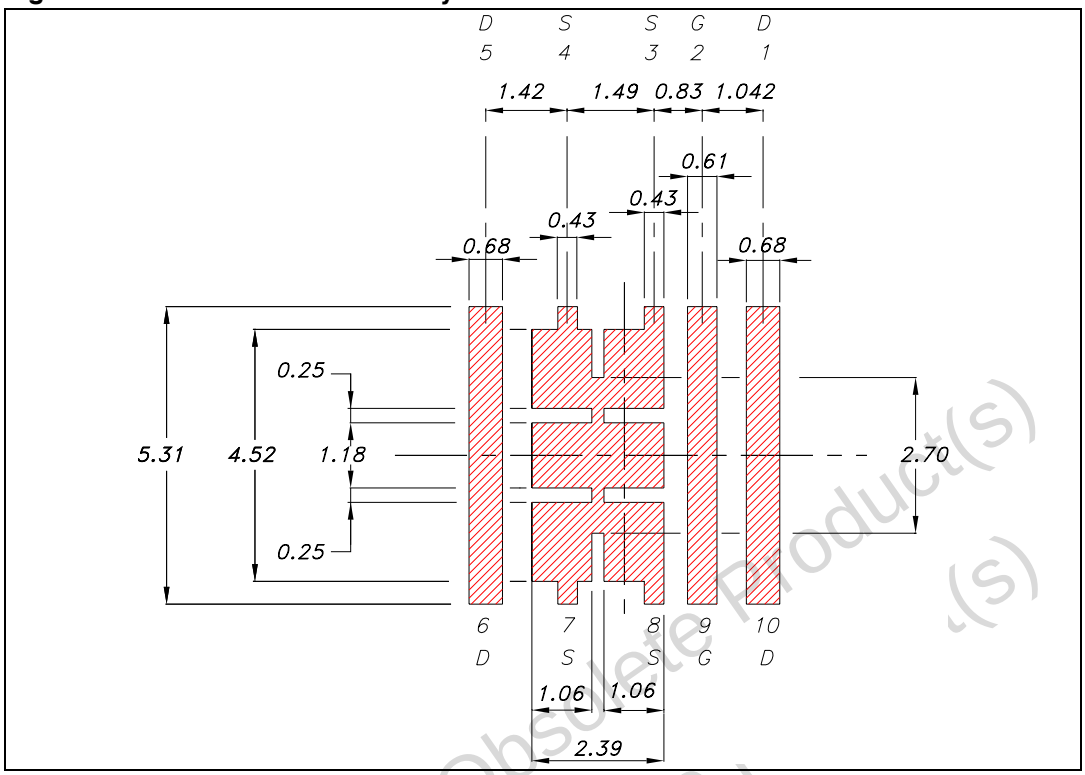
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Figure 20. PolarPAK® (option "L") drawings



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Obsolete Pro

Figure 21. Recommended PAD layout



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5 Revision history

Table 9. Document revision history

Date	Revision	Changes
01-Jul-2008	1	First release
16-Apr-2009	2	Document status promoted from preliminary data to datasheet

Obsolete Product(s) - Obsolete Product(s)
Obsolete Product(s) - Obsolete Product(s)

Obsolete Product(s) - Obsolete Product(s)

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